

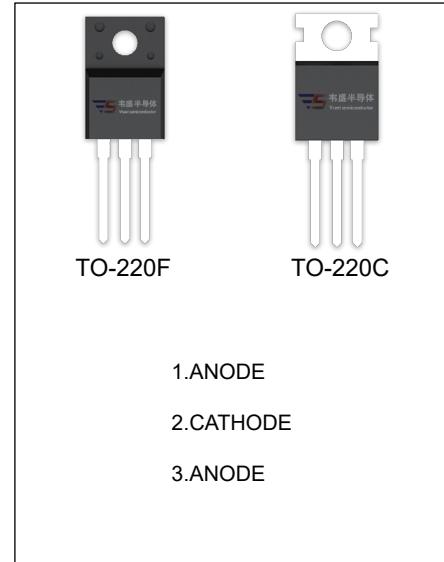
SBD3045CT、SBDF3045CT SCHOTTKY BARRIER RECTIFIER

MAIN CHARACTERISTICS

I_o	30 (2×15) A
V_{RRM}	45 V
T_j	150 °C
$V_{F(ty)}$	0.58V (@ $T_j=125^{\circ}\text{C}$)

FEATURES

- Low Power Loss, High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop



MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	SBD		Unit
		3045CT	F3045CT	
V_{RRM}	Peak repetitive reverse voltage			
V_{RWM}	Working peak reverse voltage		45	V
V_R	DC blocking voltage			
$V_{R(RMS)}$	RMS reverse voltage		31.5	V
I_o	Average rectified output current		30	A
I_{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)		200	A
$R_{\Theta JC}$	Thermal resistance from junction to case , $T_c=25^{\circ}\text{C}$	2.0	3.0	°C/W
$R_{\Theta JA}$	Thermal resistance from junction to ambient		62.5	°C/W
T_j	Junction temperature		150	°C
T_{stg}	Storage temperature		-55~+150	°C

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions		Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=0.1\text{mA}$		45			V
Reverse current	I_R	$V_R=45\text{V}$	$T_j = 25^{\circ}\text{C}$		20	100	uA
			$T_j = 125^{\circ}\text{C}$		10		mA
Forward voltage	V_F	$I_F=10\text{A}$	$T_j = 25^{\circ}\text{C}$		0.55	0.6	V
			$T_j = 125^{\circ}\text{C}$		0.50		V
		$I_F=15\text{A}$	$T_j = 25^{\circ}\text{C}$		0.62	0.7	V
			$T_j = 125^{\circ}\text{C}$		0.58		V

*Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2.0\%$.

FIG.1: FORWARD CURRENT DERATING CURVE

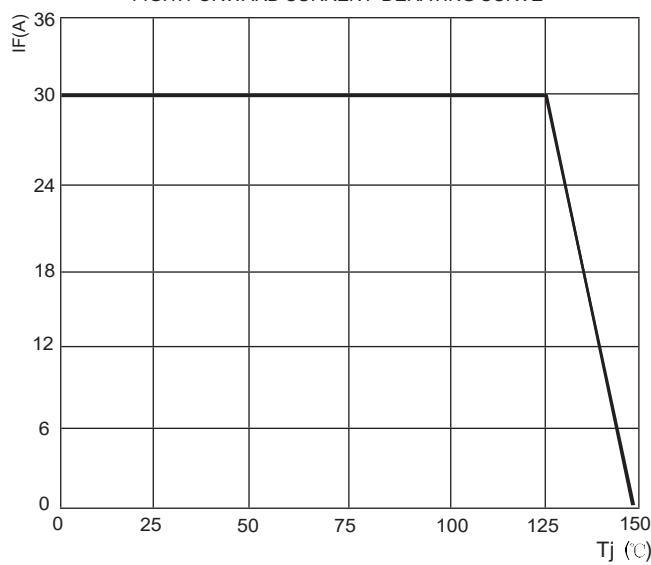


FIG.2: TYPICAL FORWARD CHARACTERISTICS

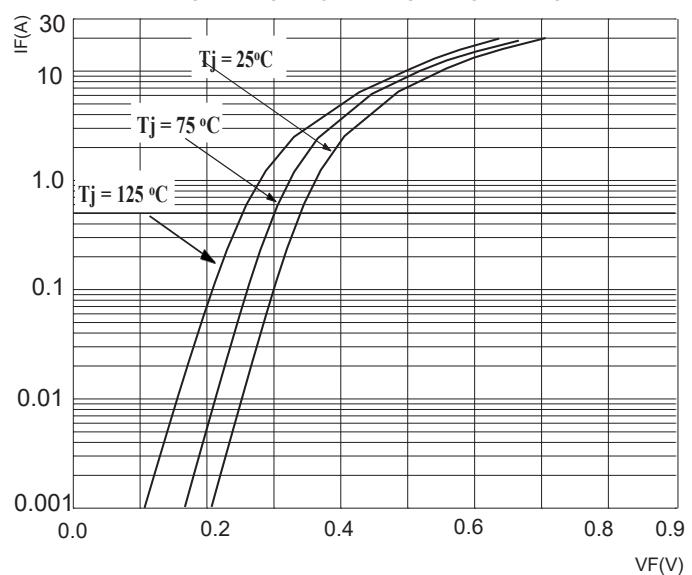


FIG.3: TOTAL CAPACITANCE DERATING CURVE

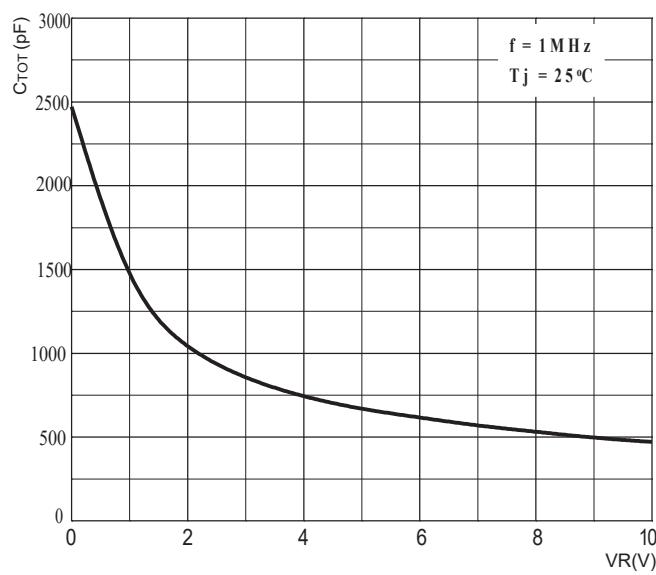


FIG.4: TYPICAL REVERSE CHARACTERISTICS

